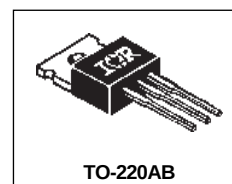


32CTQ030

SCHOTTKY RECTIFIER

30 Amp



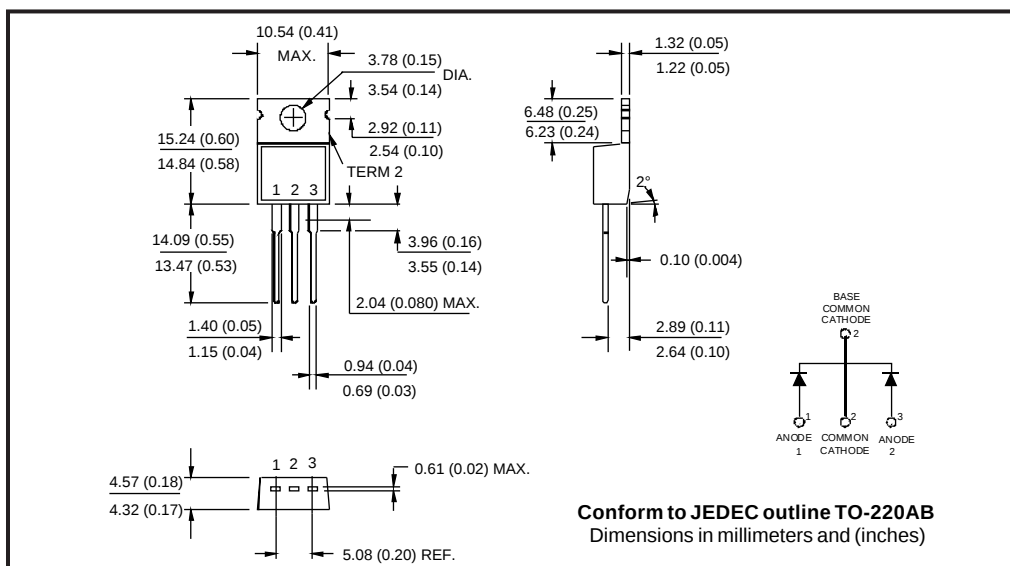
Major Ratings and Characteristics

Characteristics	32CTQ030	Units
$I_{F(AV)}$ Rectangular waveform	30	A
V_{RRM}	30	V
I_{FSM} @ $t_p = 5 \mu s$ sine	900	A
V_F @ 15 Apk, $T_J = 125^\circ C$ (per leg)	0.40	V
T_J	-55 to 150	$^\circ C$

Description/Features

The 32CTQ030 center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to $150^\circ C$ junction temperature. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

- $150^\circ C$ T_J operation
- Center tap TO-220 package
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



32CTQ030

PD-2.267 rev. B 10/98

International
IR Rectifier

Voltage Ratings

Part number	32CTQ030
V_R Max. DC Reverse Voltage (V)	30
V_{RWM} Max. Working Peak Reverse Voltage (V)	

Absolute Maximum Ratings

Parameters		32CTQ	Units	Conditions	
I _{F(AV)}	Max. Average Forward Current * See Fig. 5	30	A	50% duty cycle @ T _C = 115°C, rectangular wave form	
I _{FSM}	Max. Peak One Cycle Non-Repetitive Surge Current (Per Leg) * See Fig. 7	900	A	5μs Sine or 3μs Rect. pulse	Following any rated load condition and with rated V _{RRM} applied
		250		10ms Sine or 6ms Rect. pulse	
E _{AS}	Non-Repetitive Avalanche Energy (Per Leg)	13	mJ	T _J = 25 °C, I _{AS} = 3 Amps, L = 2.90 mH	
I _{AR}	Repetitive Avalanche Current (Per Leg)	3	A	Current decaying linearly to zero in 1μsec Frequency limited by T _J max. V _A = 1.5 x V _R typical	

Electrical Specifications

Parameters		32CTQ	Units	Conditions	
V _{FM}	Max. Forward Voltage Drop (Per Leg) * See Fig. 1 (1)	0.49	V	@ 15A	T _J = 25 °C
		0.58	V	@ 30A	
		0.40	V	@ 15A	T _J = 125 °C
		0.53	V	@ 30A	
I _{RM}	Max. Reverse Leakage Current (Per Leg) * See Fig. 2 (1)	1.75	mA	T _J = 25 °C	V _R = rated V _R
		97	mA	T _J = 125 °C	
V _{F(TO)}	Threshold Voltage	0.233	V	T _J = T _J max.	
r _t	Forward Slope Resistance	9.09	mΩ		
C _T	Max. Junction Capacitance (Per Leg)	1300	pF	V _R = 5V _{DC} ; (test signal range 100Khz to 1Mhz) 25°C	
L _S	Typical Series Inductance (Per Leg)	8.0	nH	Measured lead to lead 5mm from package body	
dv/dt	Max. Voltage Rate of Change (Rated V _R)	10,000	V/ μs		

(1) Pulse Width < 300 μs , Duty Cycle < 2%

Thermal-Mechanical Specifications

Parameters		32CTQ	Units	Conditions
T _J	Max. Junction Temperature Range	-55to150	°C	
T _{stg}	Max. Storage Temperature Range	-55to150	°C	
R _{thJC}	Max. Thermal Resistance Junction to Case (Per Leg)	3.25	°C/W	DCoperation * See Fig. 4
R _{thJC}	Max. Thermal Resistance Junction to Case (Per Package)	1.63	°C/W	DCoperation
R _{thCS}	Typical Thermal Resistance, Case to Heatsink	0.50	°C/W	Mounting surface , smooth and greased
wt	Approximate Weight	2(0.07)	g(oz.)	
T	Mounting Torque	Min.	6(5)	Kg-cm (lbf-in)
		Max.	12(10)	
Case Style		TO-220AB		JEDEC

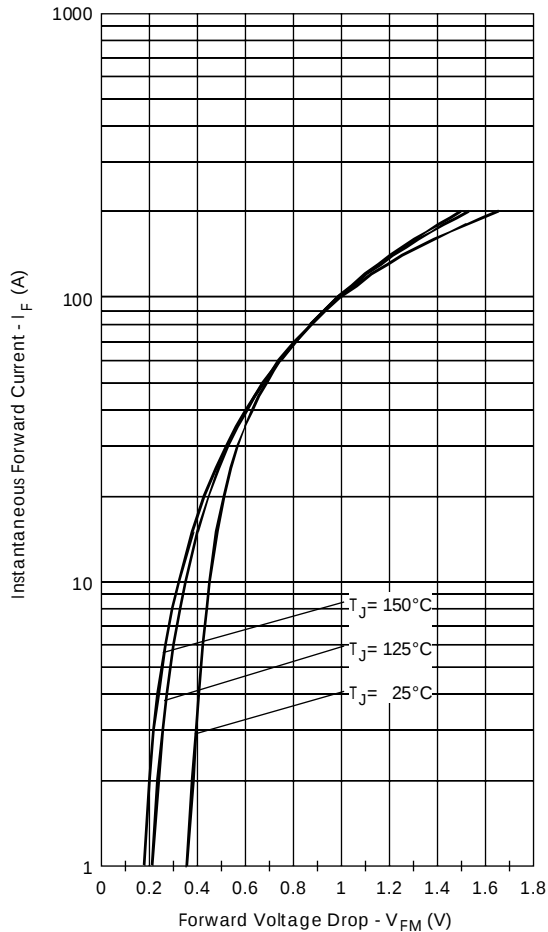


Fig. 1 - Max. Forward Voltage Drop Characteristics (PerLeg)

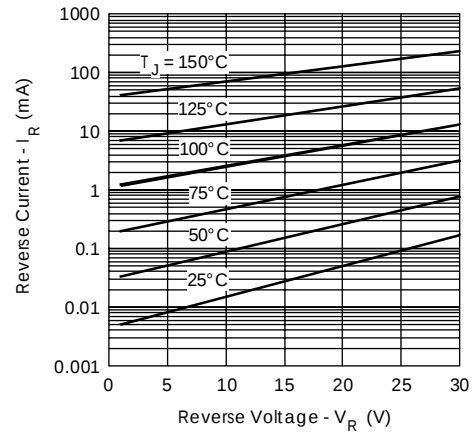


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage (Per Leg)

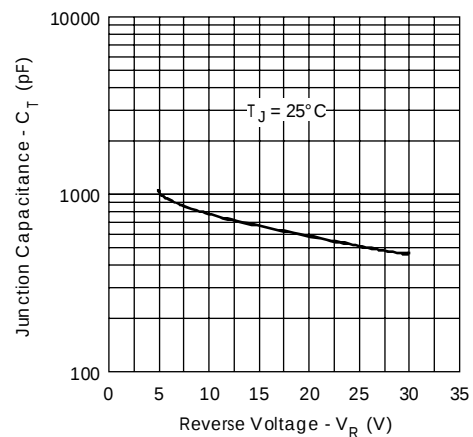


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage (Per Leg)

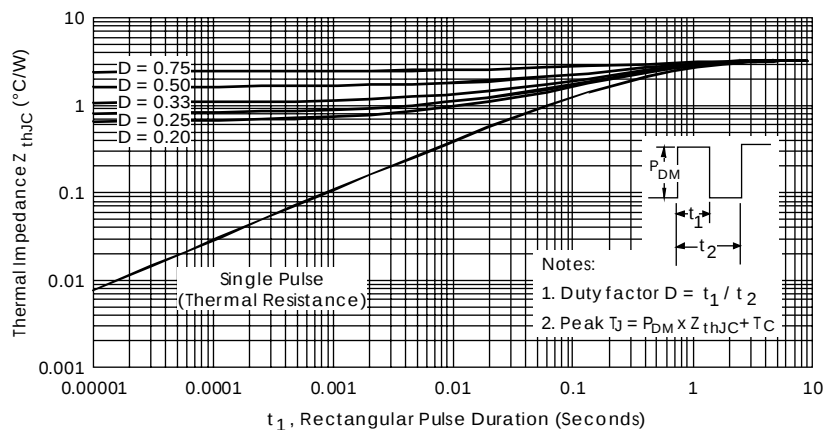


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics (Per Leg)

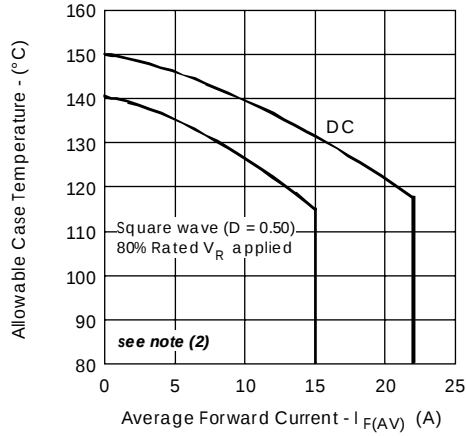


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current (Per Leg)

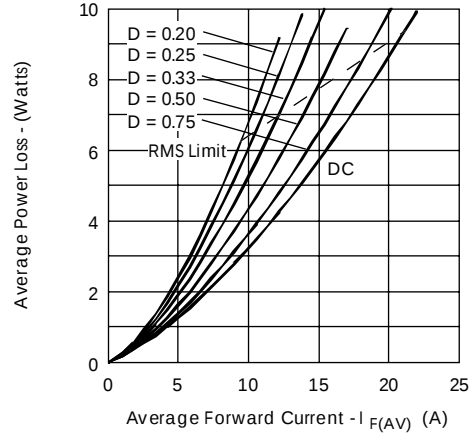


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

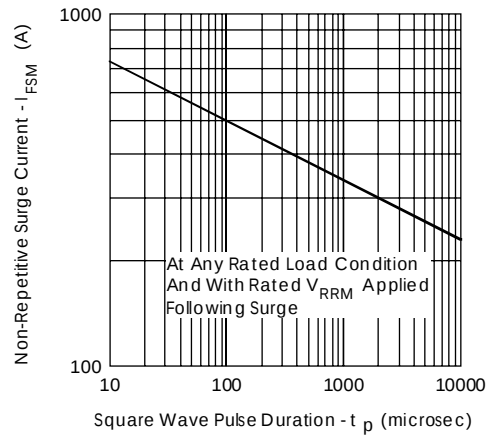


Fig. 7 - Max. Non-Repetitive Surge Current (Per Leg)

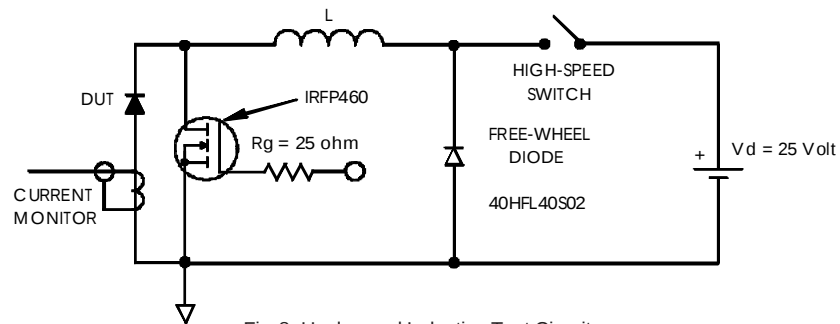


Fig. 8 - Unclamped Inductive Test Circuit

(2) Formula used: $T_c = T_j - (P_d + P_{d_{REV}}) \times R_{thJC}$;

P_d = Forward Power Loss = $I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);

$P_{d_{REV}}$ = Inverse Power Loss = $V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1} = 80\%$ rated V_R